RFUV1703

21 GHz to 26.5 GHz GaAs MMIC IQ Upconverter

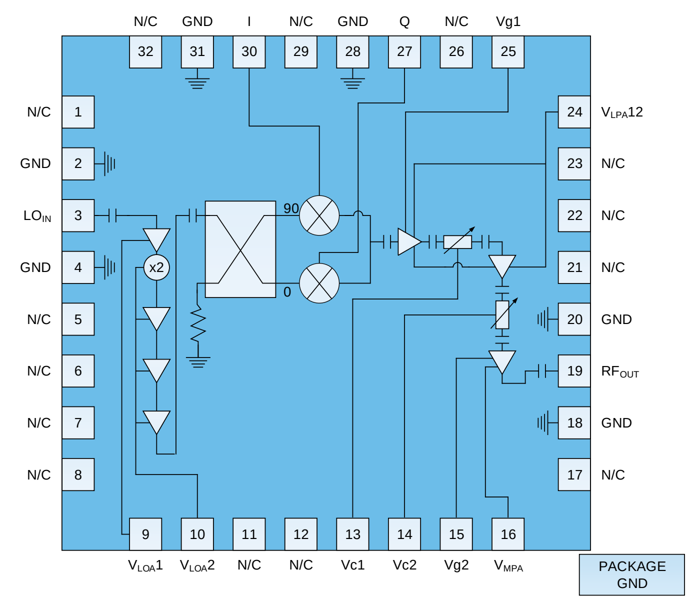
General Description

Qorvo's RFUV1703 is a 21 GHz to 26.5 GHz GaAs pHEMT upconverter, incorporating an integrated doubler, LO buffer amplifier, a balanced single sideband (image rejection) mixer followed by Variable Gain Amplifier, DC decoupling capacitors. The combination of high performance part and low-cost packaging makes the RFUV1703 a cost effective solution, ideally suited to both current and next generation point-to-point and V_{SAT} applications. RFUV1703 is packaged in a 5 mm x 5 mm QFN to simplify both system level board design and volume assembly.

Lead-free and RoHS compliant

Package: QFN, 32 Pin, 5 mm x 5 mm x 0.95 mm

Functional Block Diagram



Product Features

- RF Frequency: 21 GHz to 26.5 GHz
- LO Frequency (LSB): 10.5 GHz to 15.2 GHz
- LO Frequency (USB): 8.5 GHz to 13.25 GHz
- IF Frequency: DC to 4 GHz
- Conversion Gain (Max): 21 dB
- Conversion Gain (Min): -10 dB
- NF (Max. Gain): 12 dB
- OIP3 (Max. Gain): +27 dBm
- Image Rejection: 15 dBc

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Applications

- Point-to-Point
- V_{SAT}

Ordering Information

Part	Description
RFUV1703S2	2-Piece Sample Bag
RFUV1703SB	5-Piece Bag
RFUV1703SQ	25-Piece Bag
RFUV1703SR	100 Pieces on 7" reel
RFUV1703TR7	750 Pieces on 7" reel
RFUV1703PCBA-410	Evaluation Board

Absolute Maximum Ratings

Parameter	Rating	Unit
LPA Drain Voltage V_D	6	V
LOA Drain Voltage	6	V
IF Input Power	15	dBm
LO Input Power	15	dBm
Storage Temperature	-65 to +150	°C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Nominal Operating Parameters

Parameter	Specification			Units	Condition
	Min	Typical	Max		
RF Frequency	21		26.5	GHz	
LO Frequency: LSB	10.5		15.25	GHz	
LO Frequency: USB	8.5		13.25	GHz	
IF Frequency	DC	2.5	4.0	GHz	
LO input Drive		0		dBm	
Conversion Gain (Max.) (USB)	19	21		dB	LO = 9.95 GHz & 11.5 GHz
Conversion Gain (Min.) (USB)	-5.5	-5		dB	LO = 9.95 GHz & 11.5 GHz
OIP3 (Max. Gain) (USB)	23.5	29		dBm	LO = 9.95 GHz
OIP3 (-5 dB Gain) (USB)	0.5	6.5		dBm	LO = 9.95 GHz
OIP3 (Max. Gain) (USB)	20.5	27		dBm	LO = 11.5 GHz
OIP3 (-5 dB Gain) (USB)	4	9		dBm	LO = 11.5 GHz
Image Rejection (Max. Gain) (USB)	15	20		dBc	LO = 9.95 GHz
Image Rejection (Max. Gain) (USB)	14	20		dBc	LO = 11.5 GHz
LO Leakage @ RF-Port (Max. Gain) (USB)		-10	5	dBm	LO = 9.95 GHz
LO Leakage @ RF-Port (Max. Gain) (USB)		1	7.5	dBm	LO = 11.5 GHz
NF (Max. Gain)		12		dB	
LO Return Loss		10		dB	
RF Return Loss		10		dB	
V_{LOA}		4		V	
V_{LPA}		3.5		V	
V_{MOA}		4.5		V	
I_{LOA}		205		mA	
$I_{LOA1,2}$		120		mA	
I_{MPA}		120		mA	
I_{TOTAL}		445		mA	
V_{C1}, V_{C2}	-4		0	V	
Operating Temperature	-55	25	85	°C	

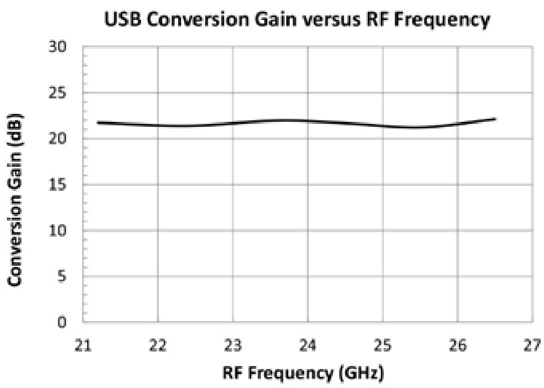
Performance Plots – USB Conversion

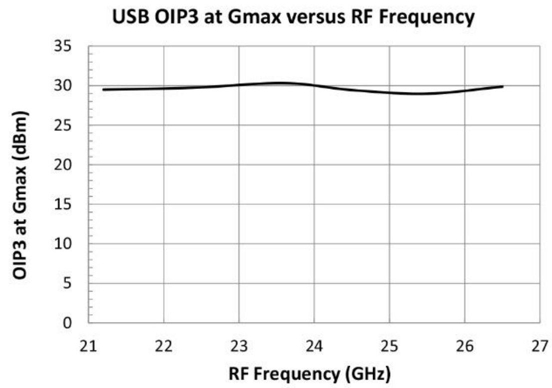
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid

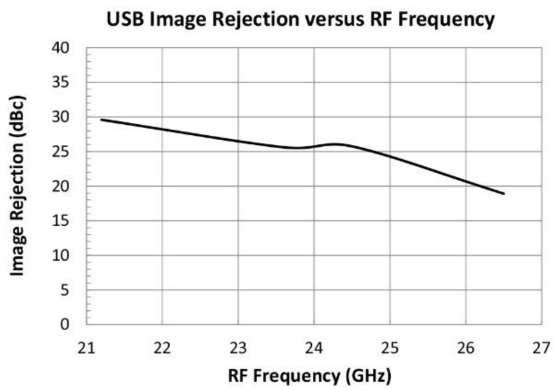
Test conditions unless otherwise noted: LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm

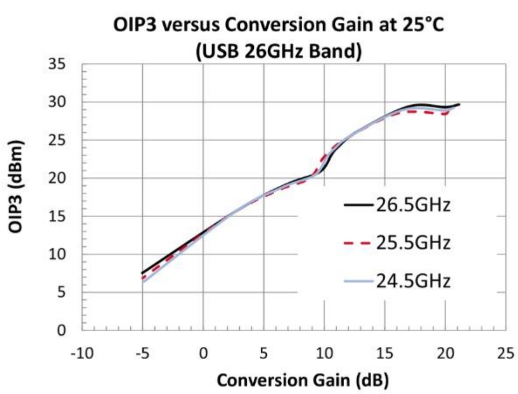
$V_{LOA1} = V_{LOA2} = 4$ V, $I_{LOA1,2} = 205$ mA; $V_{LPA12} = 3.5$ V, Adjust V_{G1} around -0.4 V to get $I_{LPA12} = 120$ mA

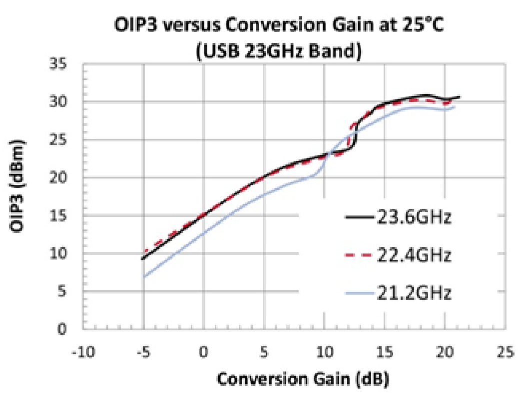
$V_{MPA} = 4.5$ V, Adjust V_{G2} to get $I_{MPA} = 120$ mA, $I_{TOTAL} = 445$ mA, $V_{C1} = V_{C2} = -4$ V











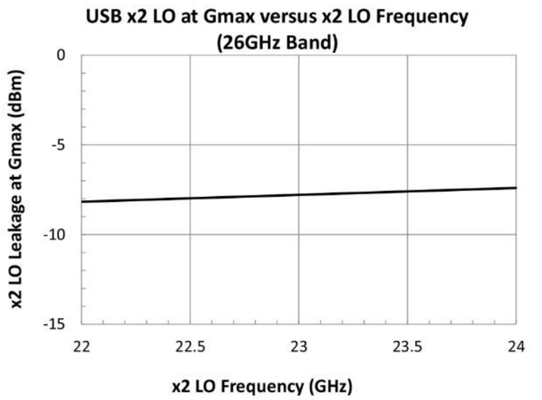
Performance Plots – USB LO Leakage & Over Temperature

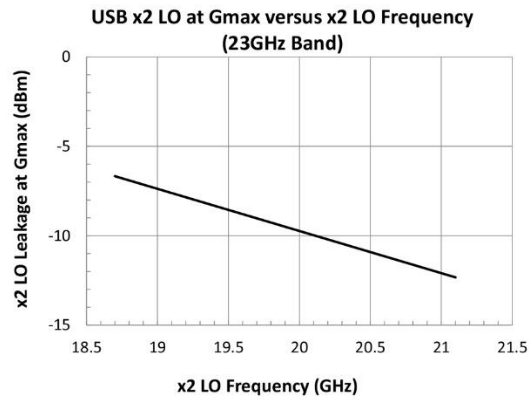
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid

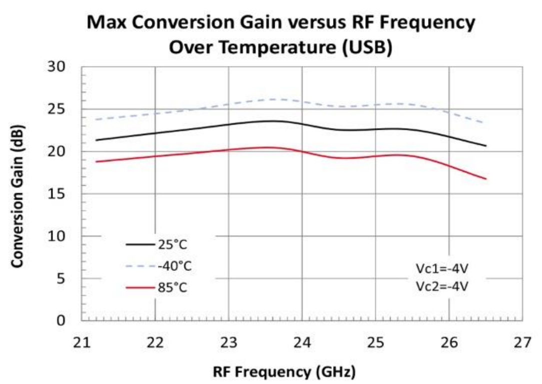
Test conditions unless otherwise noted: LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm

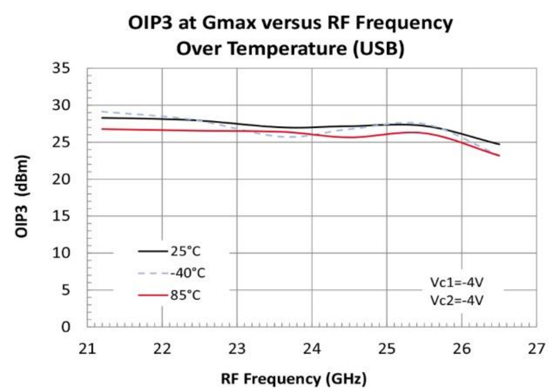
V_{LOA1} = V_{LOA2} = 4 V, $I_{LOA1,2}$ = 205 mA; V_{LPA12} = 3.5 V, Adjust V_{G1} around -0.4 V to get I_{LPA12} = 120 mA

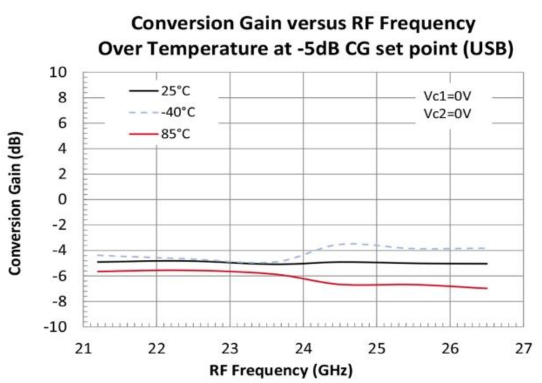
V_{MPA} = 4.5 V, Adjust V_{G2} to get I_{MPA} = 120 mA, I_{TOTAL} = 445 mA, V_{C1} = V_{C2} = -4 V

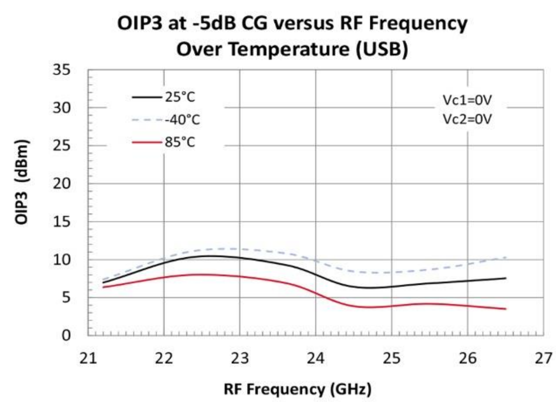












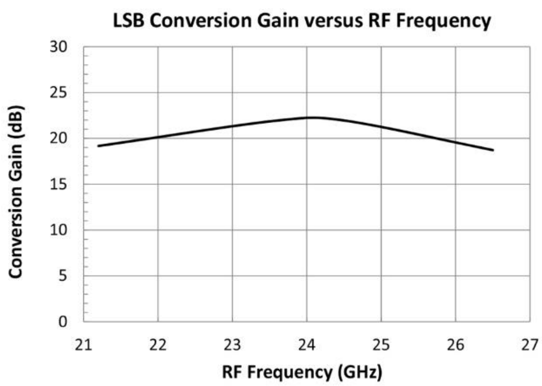
Performance Plots – LSB Conversion & LO Leakage

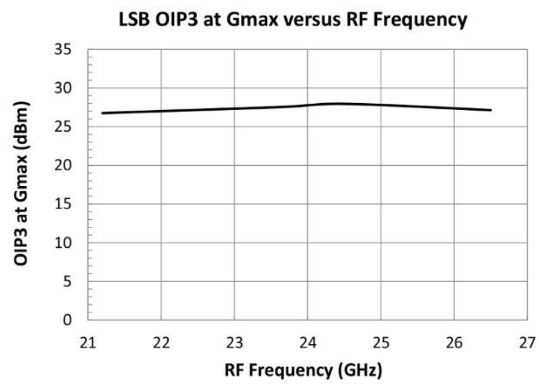
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid

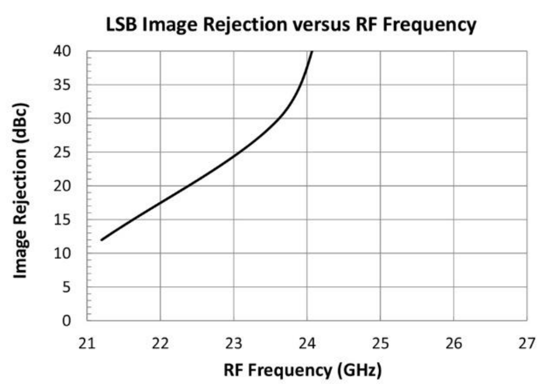
Test conditions unless otherwise noted: LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm

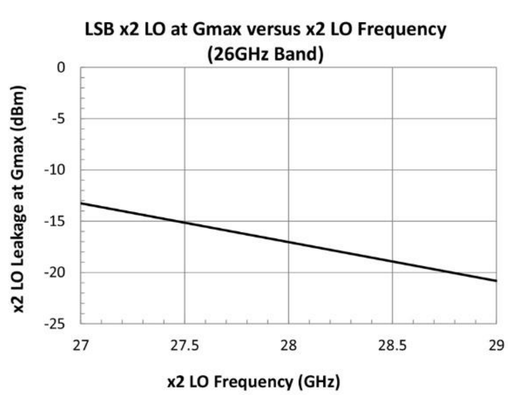
V_{LOA1} = V_{LOA2} = 4 V, $I_{LOA1,2}$ = 205 mA; V_{LPA12} = 3.5 V, Adjust V_{G1} around -0.4 V to get I_{LPA12} = 120 mA

V_{MPA} = 4.5 V, Adjust V_{G2} to get I_{MPA} = 120 mA, I_{TOTAL} = 445 mA, V_{C1} = V_{C2} = -4 V

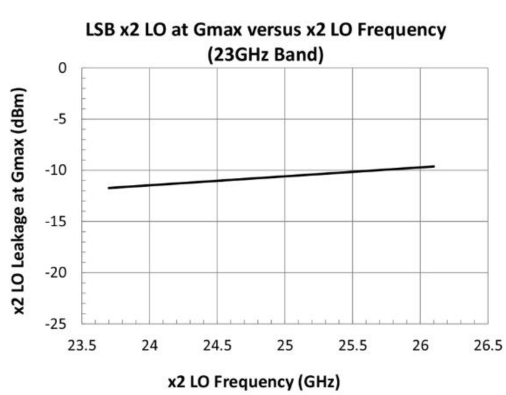








I_{BIAS} = -42mV Q_{BIAS} = 0mV



I_{BIAS} = -56mV Q_{BIAS} = 0mV

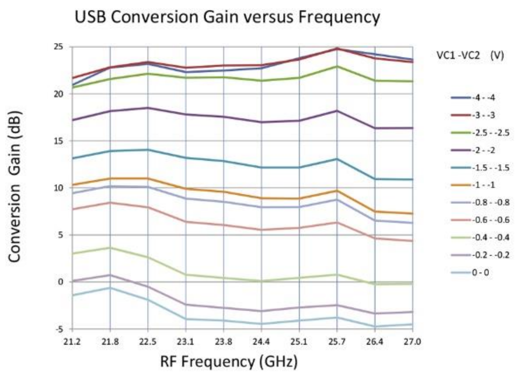
Performance Plots – USB: Without IQ Bias

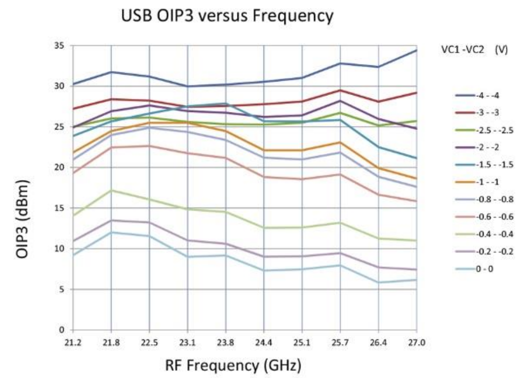
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid

Test conditions unless otherwise noted: LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm

V_{MPA} = 4.5 V, V_{LPA12} = 3.5 V, V_{LOA1} = V_{LOA2} = 4 V, I_{TOTAL} = 445 mA, V_{G1} = V_{G2} = -0.4 V

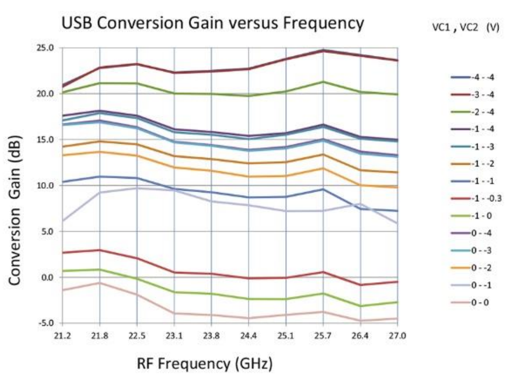
V_{C1} and V_{C2} are connected together off chip and changes over (-4 V to 0 V): **Single Control Bias**

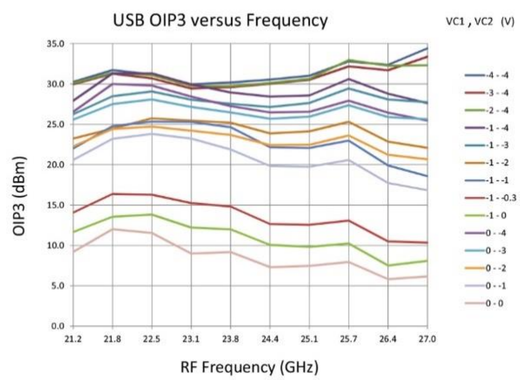




V_{MPA} = 4.5 V, V_{LPA12} = 3.5 V, V_{LOA1} = V_{LOA2} = 4 V, I_{TOTAL} = 445 mA, V_{G1} = V_{G2} = -0.4 V

V_{C1} and V_{C2} are separated controlled and changes over (-4 V to 0 V): **Double Control Bias**





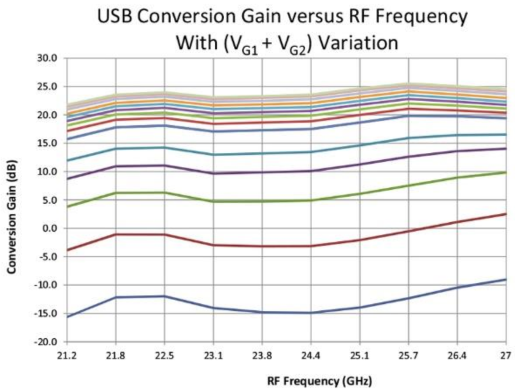
Performance Plots – USB: Without IQ Bias (continued)

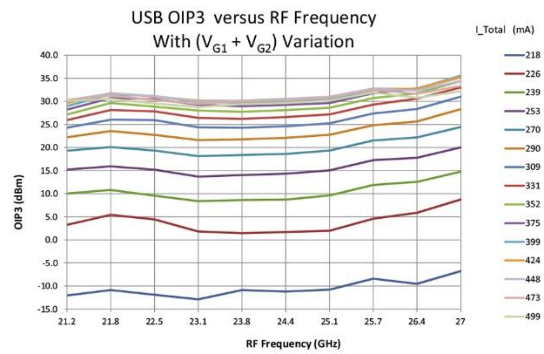
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid

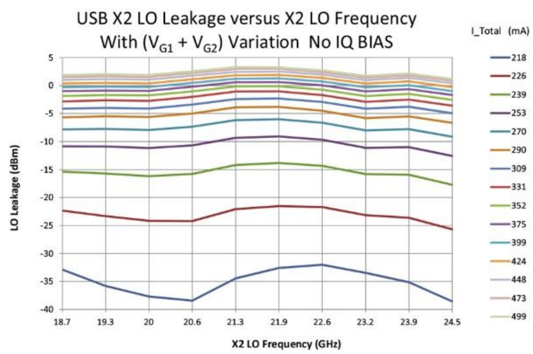
Test conditions unless otherwise noted: LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm

V_{MPA} = 4.5 V, V_{LPA12} = 3.5 V, V_{LOA1} = V_{LOA2} = 4 V, V_{C1} = V_{C2} = -4 V

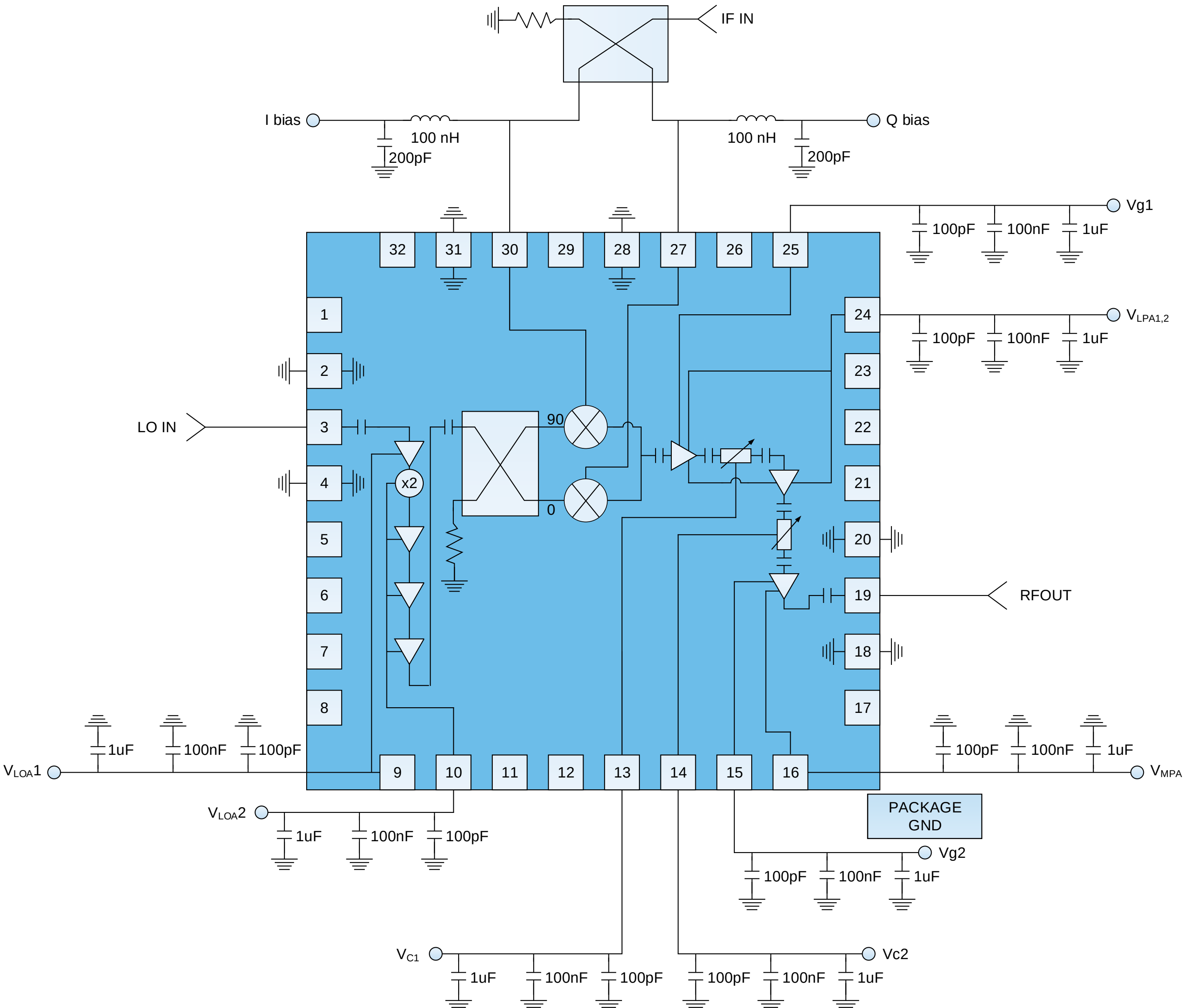
V_{G1} and V_{G2} are connected together off chip and changes over (-0.3 V to -1 V): **Single Control on V_{G1} = V_{G2}**







Application Circuit Block Diagram



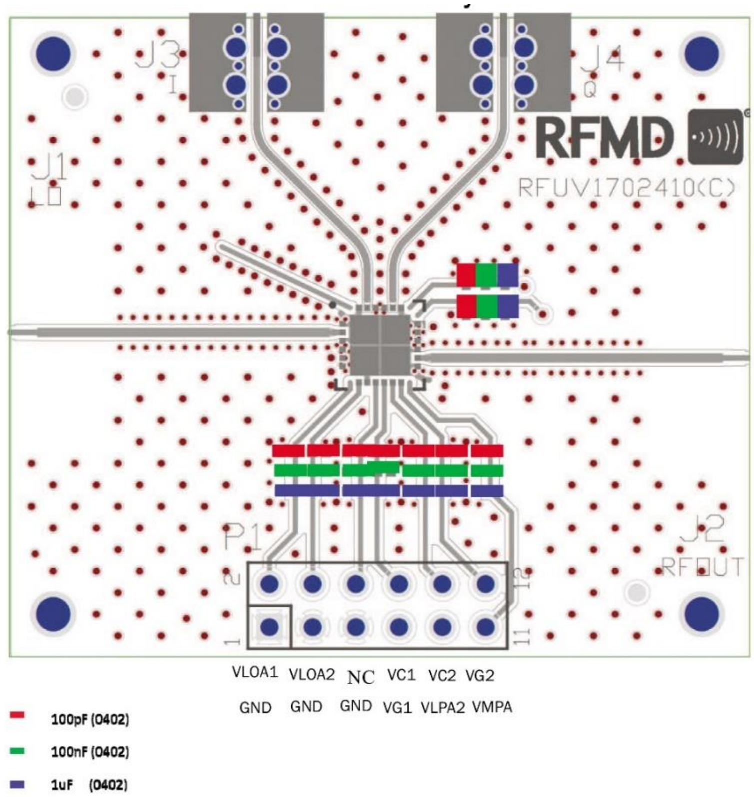
2*LO - IF = RF (LSB), LO = 10.5 to 15.25 GHz

2*LO + IF = RF (USB), LO = 8.5 GHz to 13.25 GHz

Notes:

1. External components for IQ biases are required.
2. External hybrid coupler is required.

Evaluation Board Layout



Sub-Band Frequency Ranges

Band	Frequency Range
23 GHz	21.2 GHz to 23.6 GHz
26 GHz	24.5 GHz to 26.5 GHz

Test Conditions and Bias Sequence

Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid, LO Power = 0 dBm and IF = 2.5 GHz, -10 dBm, unless otherwise stated.

$V_{LOA1} = V_{LOA2} = 4$ V, $I_{LOA1,2} = 205$ mA; $V_{LPA12} = 3.5$ V, Adjust V_{G1} around -0.4 V to get $I_{LPA12} = 120$ mA

$V_{MPA} = 4.5$ V, Adjust V_{G2} to get $I_{MPA} = 120$ mA, $I_{TOTAL} = 445$ mA, $V_{C1} = V_{C2} = -4$ V.

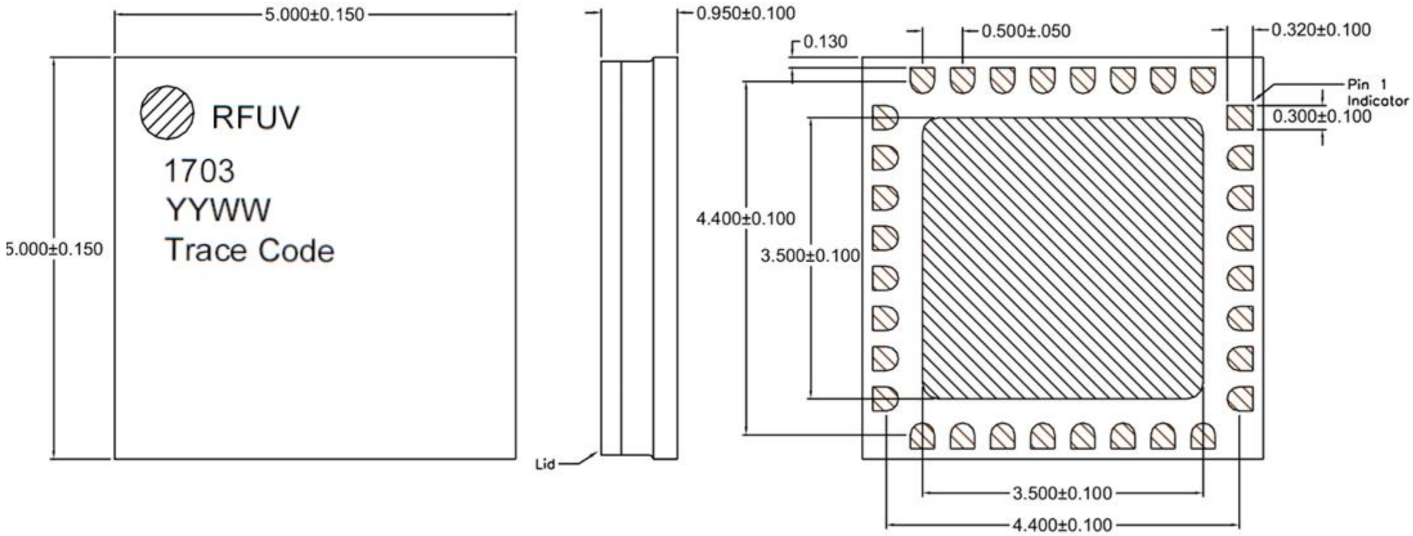
Typical Bias Sequence							
	G_{MAX}						G_{MIN}
V_{C1} (V)	-4	-2	-1	0	0	0	0
V_{C2} (V)	-4	-4	-4	-4	-2	-1	0

More dynamic range can be achieved using V_{G2} over (-0.4 to -1 V) and V_{G1} over (-0.4 to -1 V)

Pin Names and Description

Pin Number	Label	Description
1	N/C	Not Connected
2	GND	Ground
3	LO	Local Oscillator Input. AC Coupled and Matched to 50 Ω
4	GND	Ground
5	N/C	Not Connected
6	N/C	Not Connected
7	N/C	Not Connected
8	N/C	Not Connected
9	VLOA1	LOA Stage1 Drain Bias
10	VLOA2	LOA Stage2 Drain Bias
11	N/C	Not Connected
12	N/C	Not Connected
13	VC1	Control Line Number 1 (See Bias Sequence Description)
14	VC2	Control Line Number 2 (See Bias Sequence Description)
15	VG2	MPA Gate Bias
16	VMPA	MPA Drain Bias
17	N/C	Not Connected
18	GND	Ground
19	RFOUT	RF Output. AC Coupled and Matched to 50 Ω
20	GND	Ground
21	N/C	Not Connected
22	N/C	Not Connected
23	N/C	Not Connected
24	VLPA1, VLPA2	LPA Stage 1, 2 Drain Bias
25	VG1	LPA Stage 1, 2 Gate Bias
26	N/C	Not Connected
27	Q	IF Q Input
28	GND	Ground
29	N/C	Not Connected
30	I	IF I Input
31	GND	Ground
32	N/C	Not Connected

Package Marking and Dimensions



All dimensions are in millimeters

Marking:
RFUV1703: Part number
YY: Part Assembly year
WW: Part Assembly week

Assembly Notes

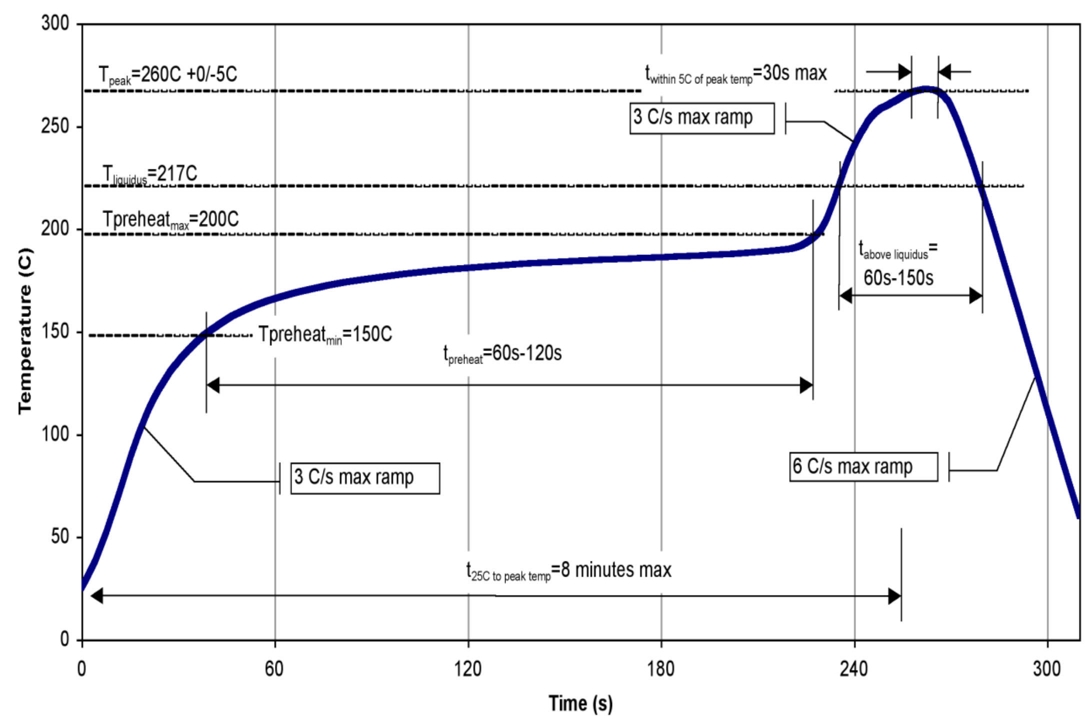
Compatible with lead-free soldering processes with 260°C peak reflow temperature.

This package is air-cavity and non-hermetic, and therefore cannot be subjected to aqueous washing. The use of no-clean solder to avoid washing after soldering is highly recommended.

Contact plating: Ni-Au.

Solder rework not recommended.

Recommended Soldering Profile



Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	JESD22-A114
ESD – Charged Device Model (CDM)	Class C2	JESDE22-C101C
MSL – Convection Reflow 260 °C	Level 2	JEDEC standard IPC/JEDEC J-STD-020

Caution!
ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_{4}0_{2}$) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: **www.qorvo.com**

Tel: **1-844-890-8163**

Email: **customer.support@qorvo.com**

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